## NSN 5962-01-400-6120

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-400-6120 **Body Length:** 1.290 inches **Body Width:** 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.04 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and schottky and programmable and bipolar and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Bipolar metal-oxide semiconductor **Case Outline Source And Designator:** D-3 mil-m-38510 **Current Rating Per Characteristic:** 100.00 milliamperes forward current, peak total value not applicable **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 55.00 nanoseconds access **Memory Device Type: Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

Fiig:

A458a0